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# **Design of a Time Gain Compensation Amplifier for an Ultrasound Analog Receiver Front End Using 0.18 $\mu\text{m}$ SOI Process**

**Budi Mulyanto**

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# Content

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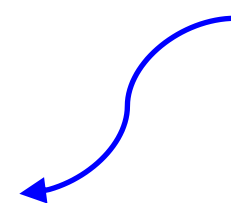
- CMUT and Measurement Principle of Ultrasound Systems
- System Level Considerations
- Top Level Simulation Results
- Suggested Improvements

# Capacitive Micromachined Ultrasonic Transducers

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$$C = \epsilon_0 \frac{A}{d}$$

The impinging echoes  
change the distance

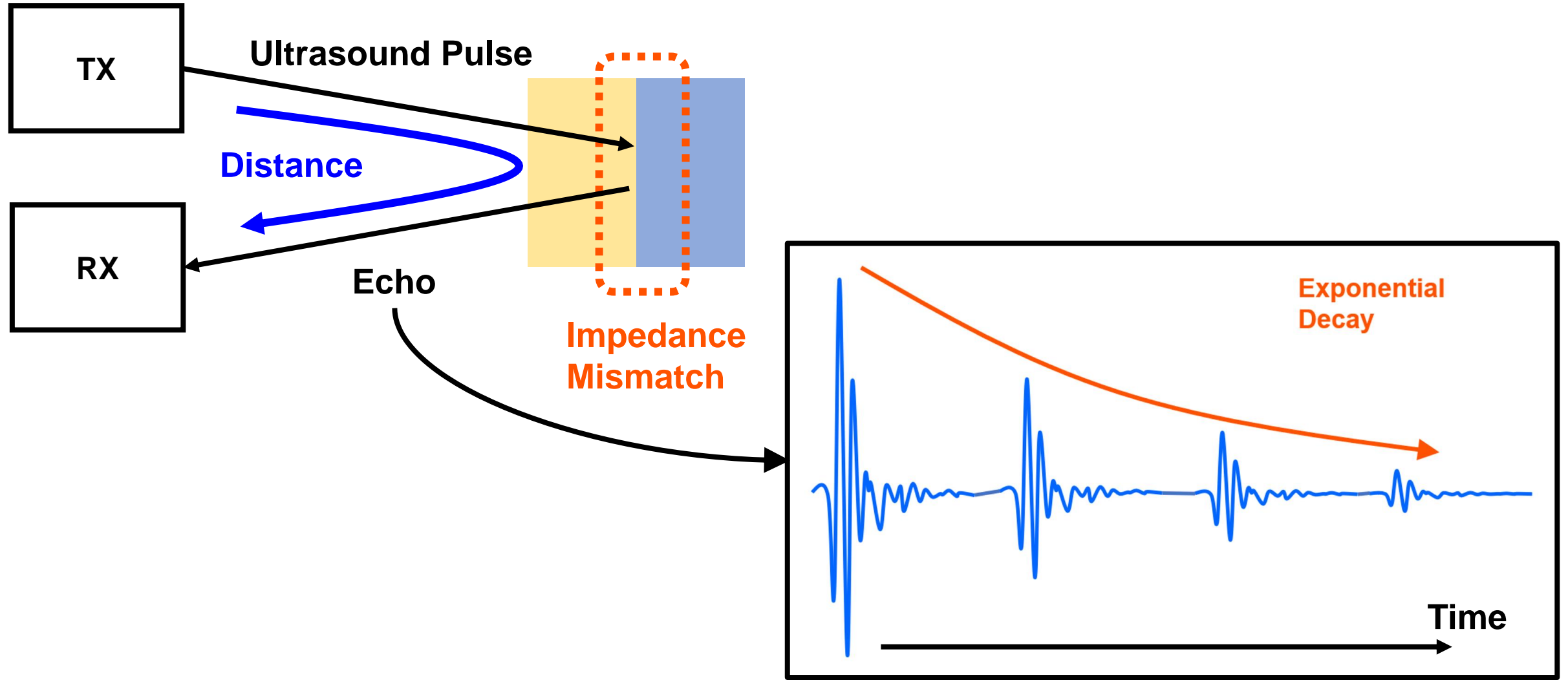


$$\frac{dCV}{dt} = C \frac{dV}{dt} + V \frac{dC}{dt} = \frac{dQ}{dt} = i_{CMUT}$$

We want to  
measure this.



# Measurement Principle and Time-Gain Compensation



# Block Diagram

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**Single** stage, including variable gain and linear-in-dB features [1]

- **Interpolation technique**
- complex analog controller to steer the biasing current.



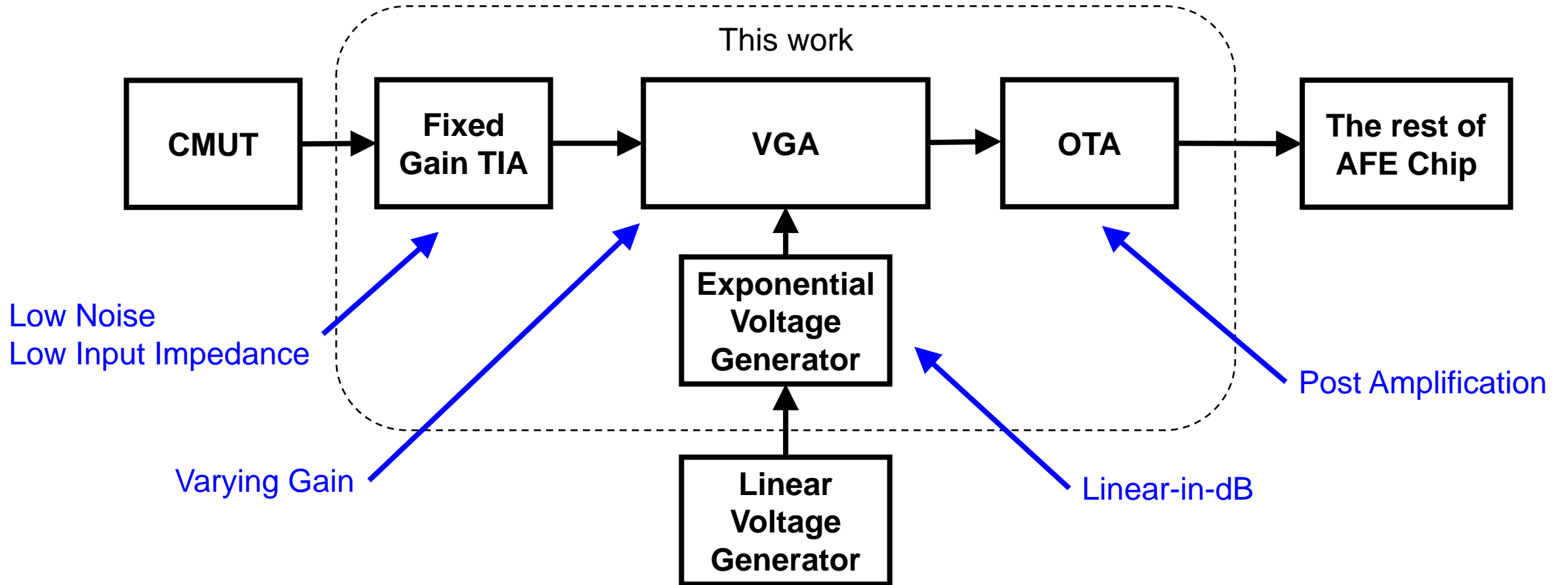
# System Level Considerations

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Challenges	Solutions	Circuits
Echo attenuation	Variable gain	VGA : Folded Gilbert Cell
Exponential attenuation profile	Exponential gain variation	Exponential Voltage Generator
High (output) impedance sensor	Low input impedance front end	Common gate topology (and its derivatives)
Low noise is expected	Allocate high gain at the first stage	LNA : Regulated Cascode
Low VGA gain	Post amplifier	Post Amp : Symmetrical OTA

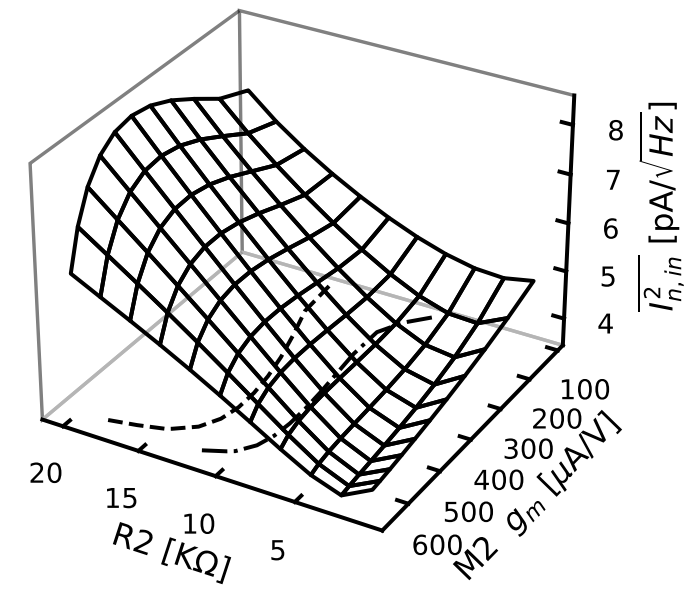
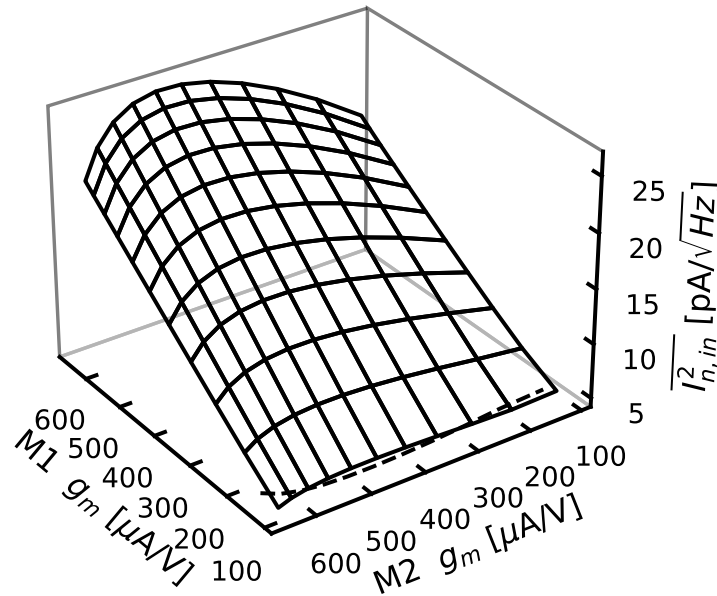
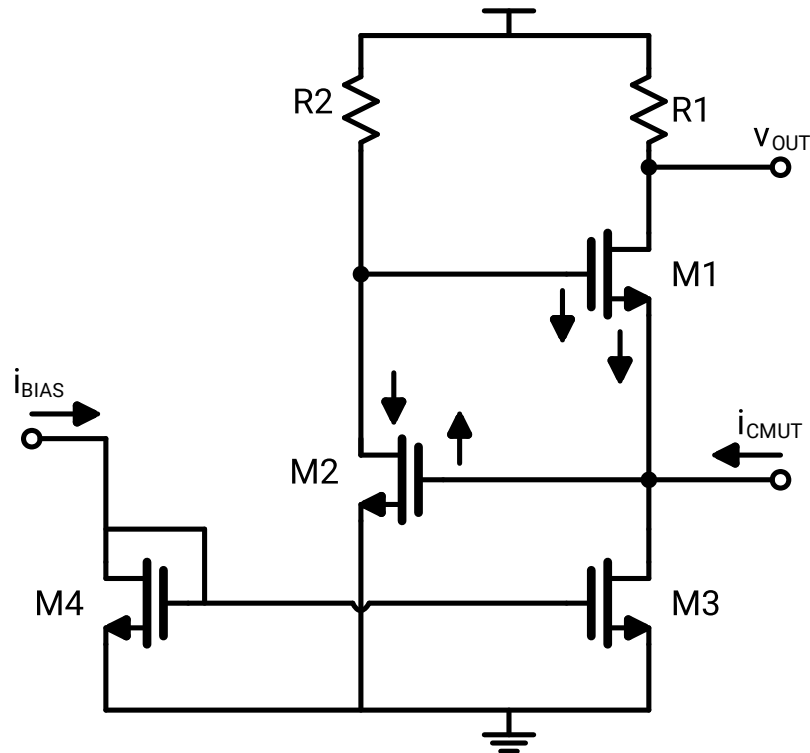
# Block Diagram

## Proposed Block Diagram



## After determining the block diagram...

- Literature research for each block
- Device characterization using gm/ID method
- Detail hand calculation and circuit performance exploration, if necessary
- Complete design workflow until post layout simulation

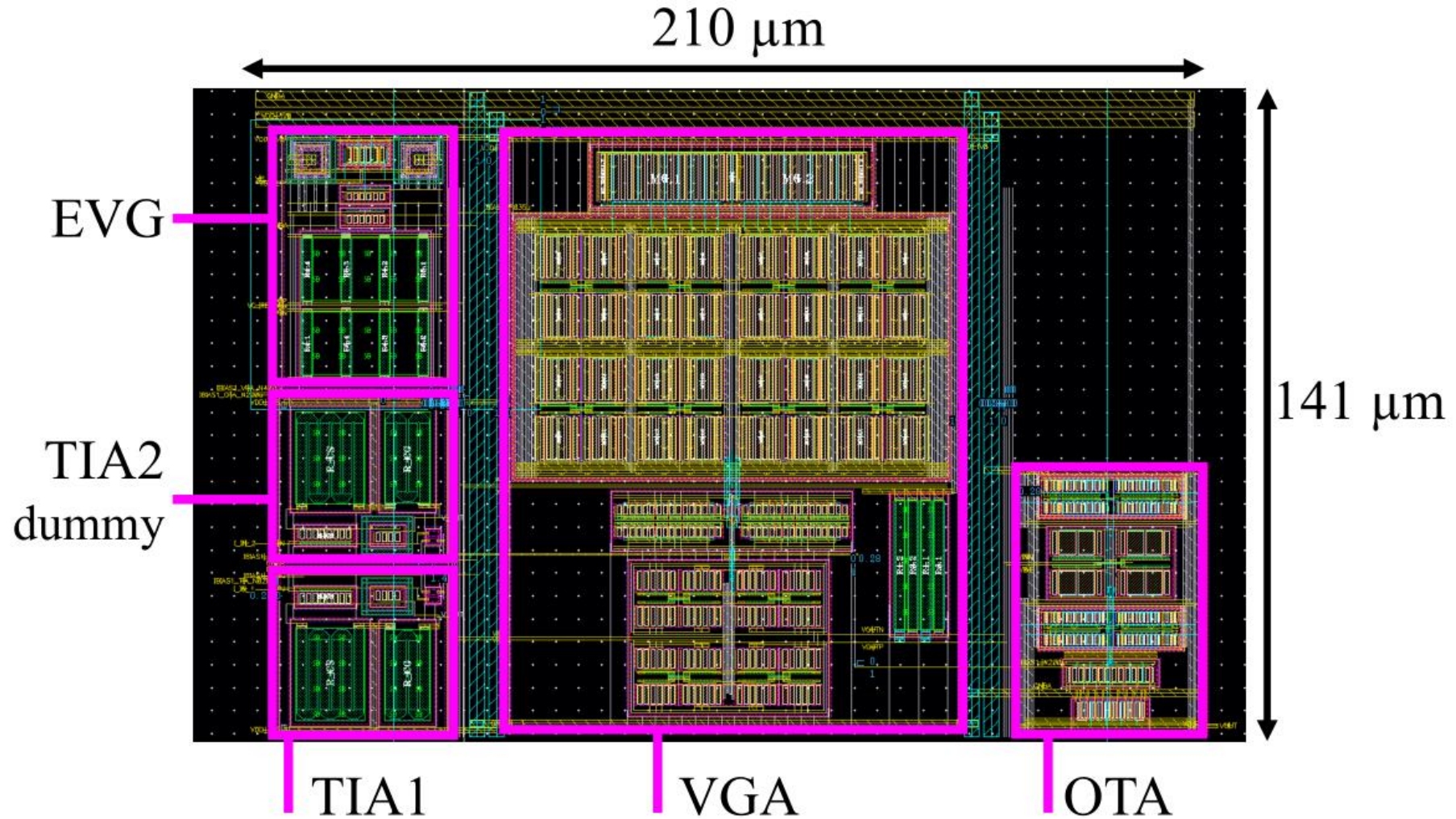


It helps me to optimize the circuit



# Top Level Circuit : Time Gain Compensation (TGC) Transimpedance Amplifier

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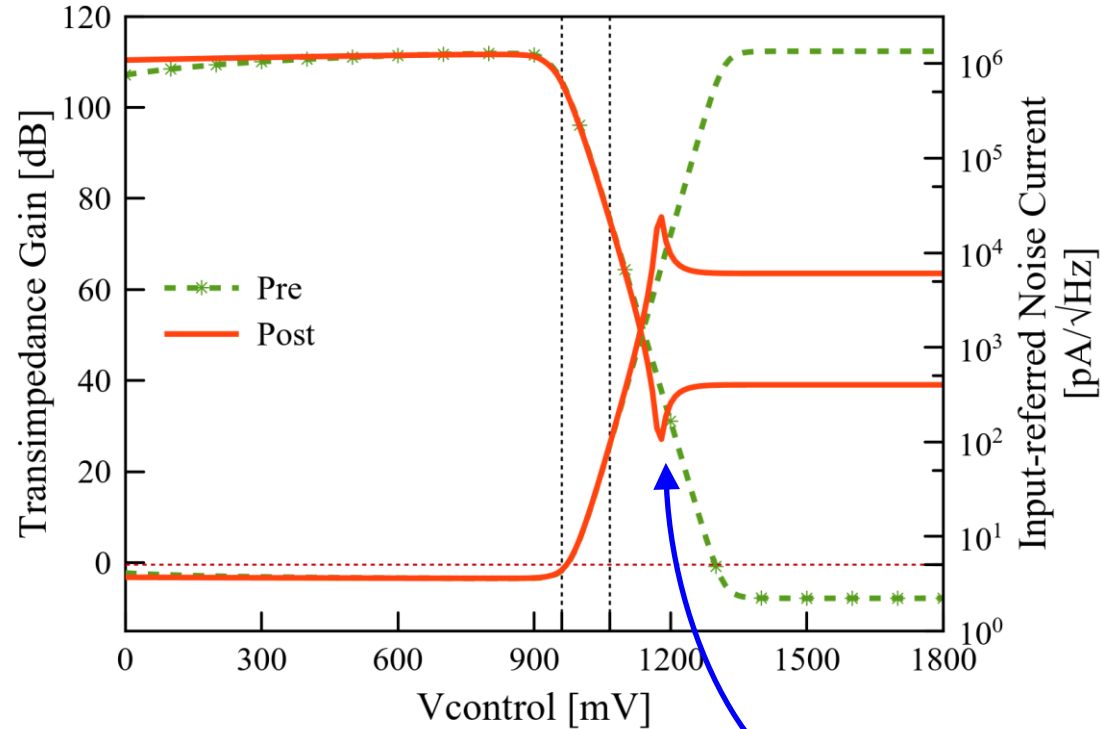
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This concludes the design phase.

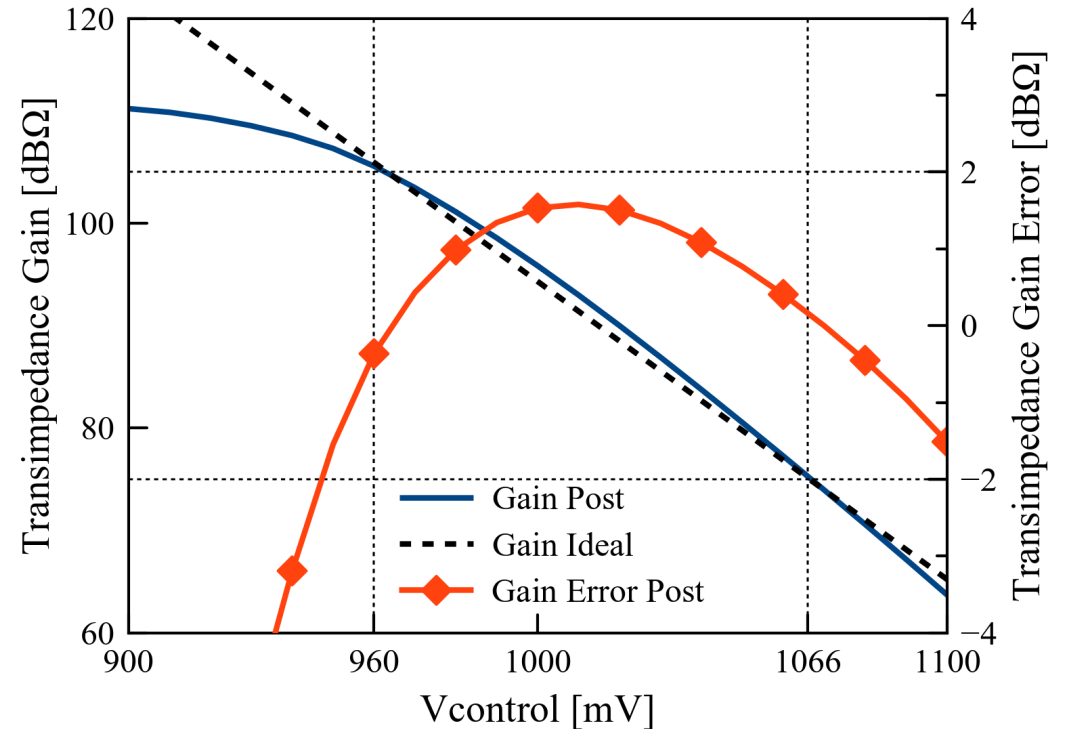
The next part will be about  
the **simulation results** and **proposed improvements**.

# Top Level Circuit : Time Gain Compensation (TGC) Transimpedance Amplifier

## Post Layout DC Simulation

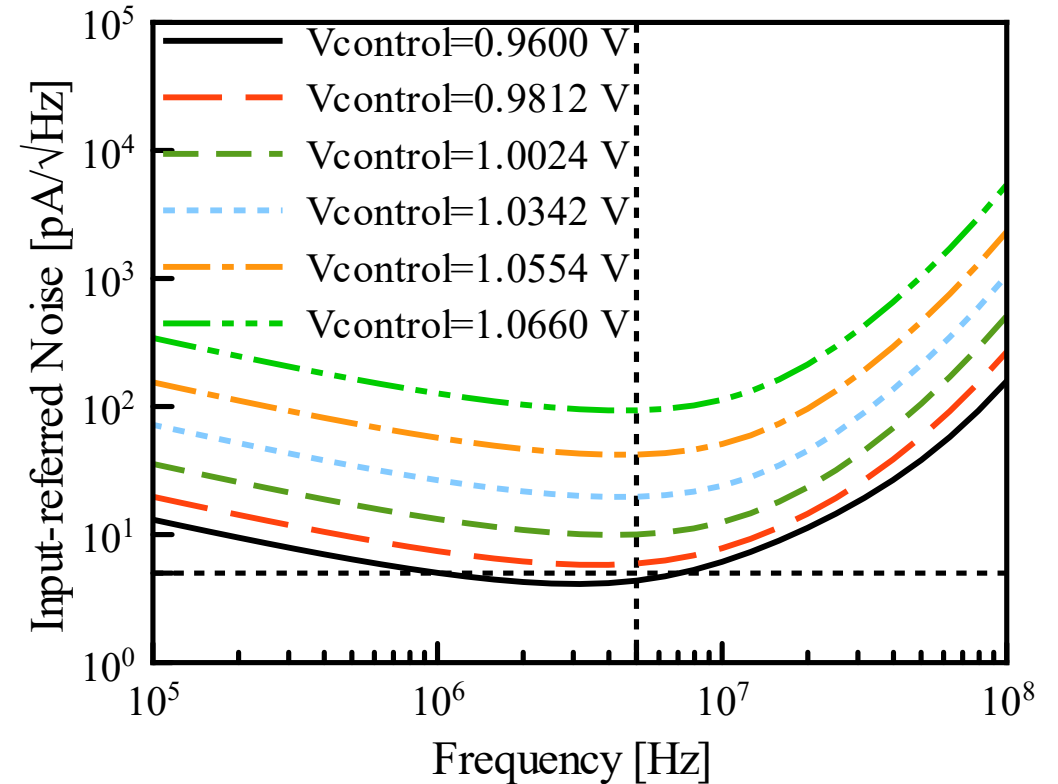
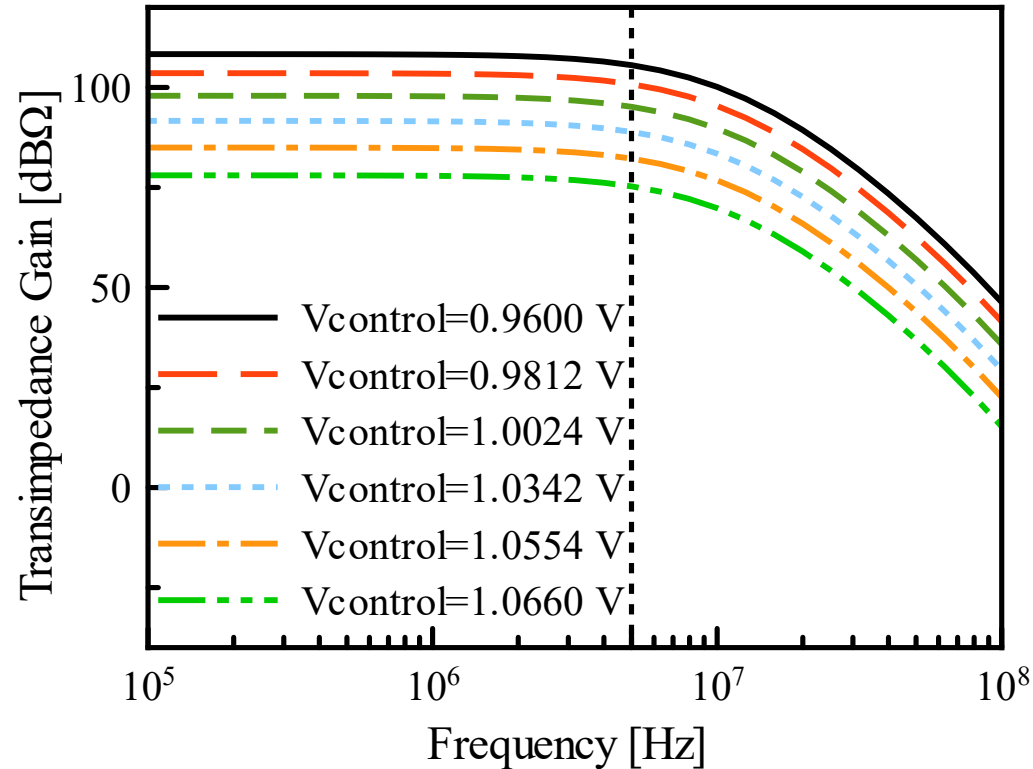


Due to parasitic components



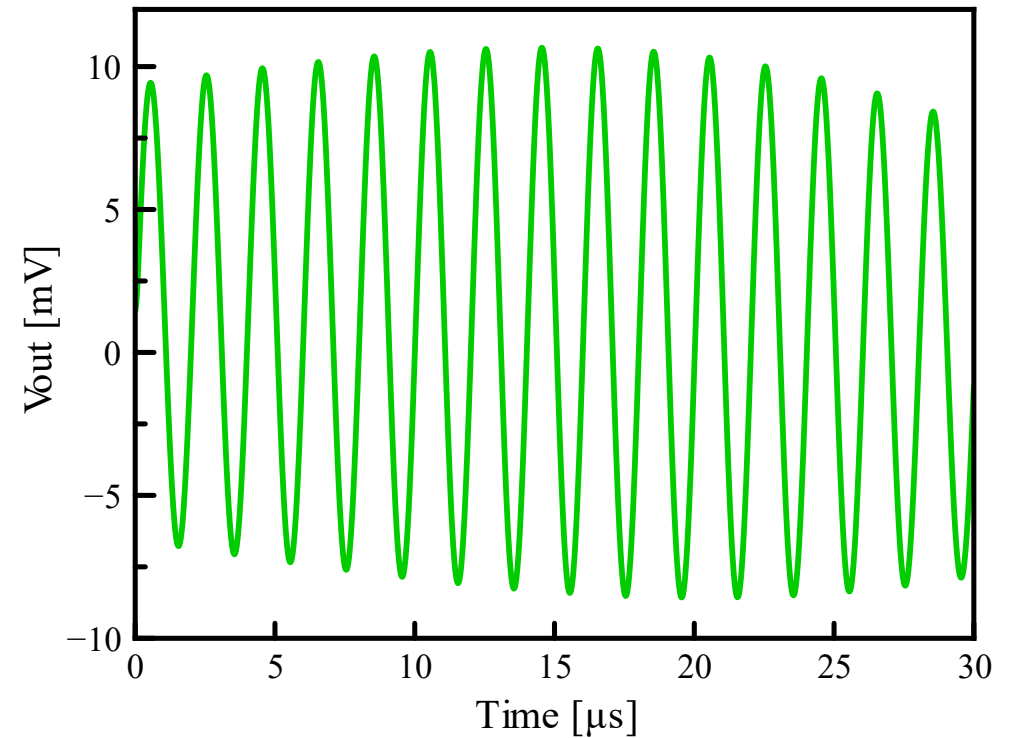
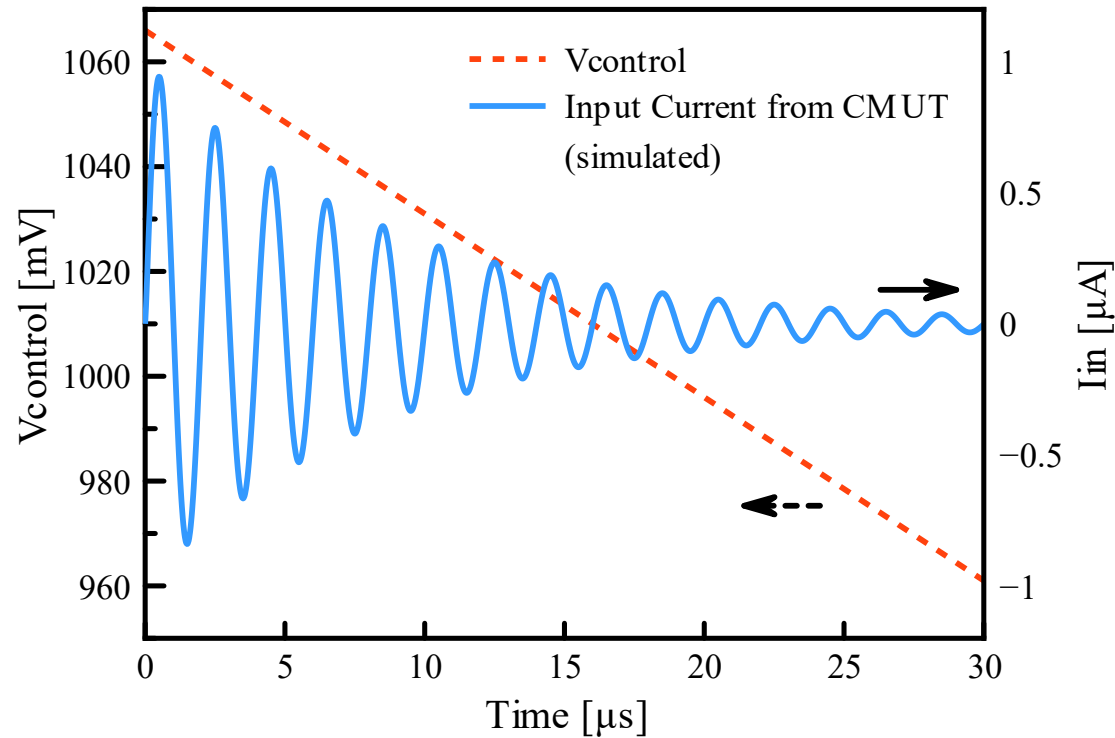
# Top Level Circuit : Time Gain Compensation (TGC) Transimpedance Amplifier

## Post Layout AC Simulation



# Top Level Circuit : Time Gain Compensation (TGC) Transimpedance Amplifier

## Post Layout Transient Simulation



# Top Level Circuit : Time Gain Compensation (TGC) Transimpedance Amplifier

Parameter	Unit	Target	This work	ISSCC2020 [3]	TBCAS2017 [40]	VLSID2020 [41]
Gain Range	[dBΩ]	$\geq 30$	30	33	18	36
Maximum Gain	[dBΩ]	$\geq 106$	108	107	97	41.6
Gain Error	[dBΩ]	-	$\pm 2$	$\pm 1$	-	$\pm 0.5$
Gain Control Type	[-]	-	Analog	Analog	Discrete	Discrete
Control Voltage Range	[mV]	-	960 – 1066	800	-	-
3dB Bandwidth	[MHz]	$\geq 5$	5	7	7.5	10-25
Input-referred Current Noise @5MHz	[pA/ $\sqrt{\text{Hz}}$ ]	$\leq 5$	4.5 - 99	1.7	4.8	-
Transducer Capacitance	[pF]	10	10	15	5.5	-
Load Capacitance	[pF]	5	2*	1.7	-	-
Power Consumption	[mW]	$\leq 6$	5.35	5.2	0.18	3.6
Area	[ $\mu\text{m}^2$ ]	-	210 x 141	400 x 400	76 x 50	320000
Process Technology	-	0.18 $\mu\text{m}$ SOI	0.18 $\mu\text{m}$ SOI	0.18 $\mu\text{m}$	65 nm	0.18 $\mu\text{m}$

[3] [10.1109/ISSCC19947.2020.9063052](#)

[40] [10.1109/TBCAS.2017.2716836](#)

[41] [10.1109/VLSID49098.2020.00034](#)



# Suggested Improvement #2 : Use PMOS input for the Symmetrical OTA

## Post Layout Corner Simulation of the Top Level Circuit

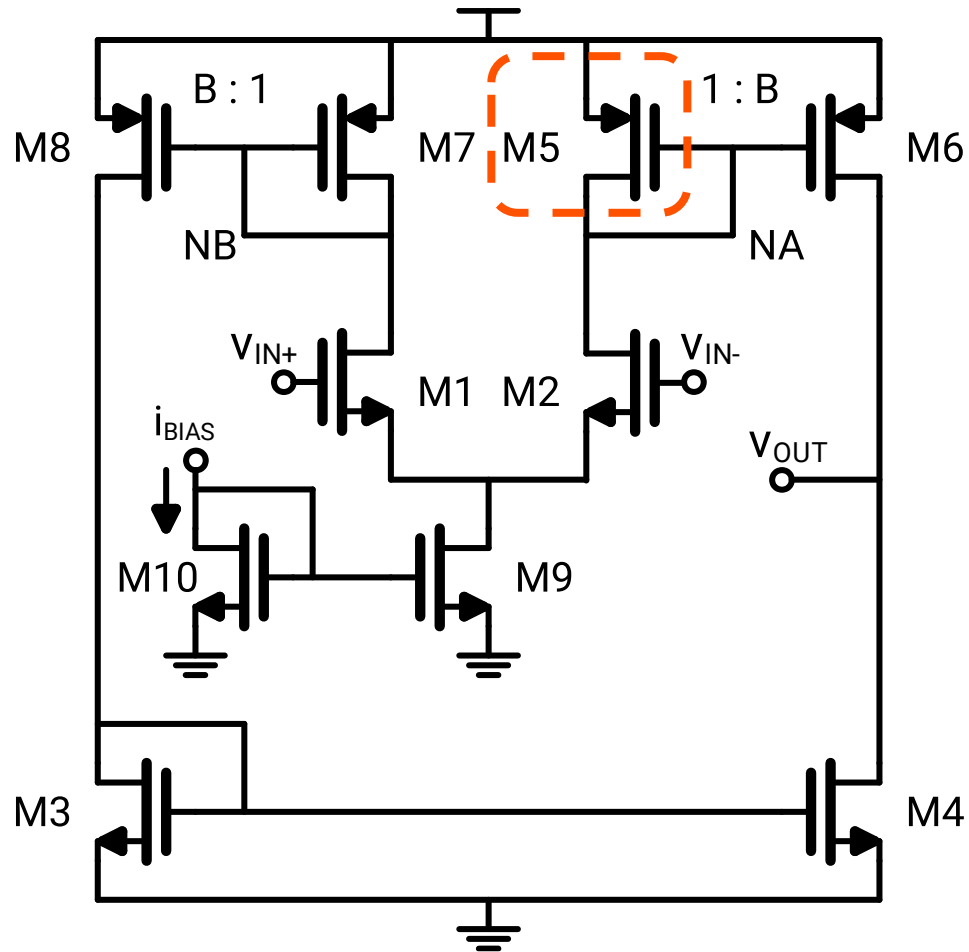
Corner	Current	Noise_@MaxGain	Noise_@MinGain	Bandwidth	Gain_@10KHz	Gain Range
Unit	[mA]	[pA/ $\sqrt{\text{Hz}}$ ]	[pA/ $\sqrt{\text{Hz}}$ ]	[MHz]	[dB $\Omega$ ]	[dB $\Omega$ ]
tm	2.780	4.366	93.36	5.263	108.3	30.30
wo	2.780	4.307	92.26	5.441	108.2	30.28
wp	2.971	4.505	99.96	5.803	106.8	30.14
ws	2.618	4.420	91.30	4.788*	109.2	30.27
wz	2.780	4.440	94.72	5.087	108.4	30.31

The noise was evaluated at 5 MHz.

\* Lower than the target value.



## Suggested Improvement #2 : Use PMOS input for the Symmetrical OTA



In addition to suggestion #1 to improve bandwidth, we also need to increase **second** pole frequency.

$$f_{2p} \approx \frac{f_{T5}}{B + 3} = 3 \times GBW$$

$$f_{T_{PMOS}} \approx \frac{1}{5} \times f_{T_{NMOS}}$$

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Thank You!